

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1
 Stylesheet Version v1.2

EPAS ID: PAT3196220

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
SATOSHI SEKINE	12/30/2014
CHEONG MIN HONG	12/10/2014
RECEIVING PARTY DATA	
Name:	FREESCALE SEMICONDUCTOR, INC.
Street Address:	6501 WILLIAM CANNON DR.
Internal Address:	TX30/OE62
City:	AUSTIN
State/Country:	TEXAS
Postal Code:	78735
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	14604323
CORRESPONDENCE DATA	
Fax Number:	(512)895-6630
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
Phone:	512-895-6979
Email:	dee.matocha@freescale.com
Correspondent Name:	FREESCALE SEMICONDUCTOR, INC.
Address Line 1:	6501 WILLIAM CANNON DR.
Address Line 2:	TX30/OE62
Address Line 4:	AUSTIN, TEXAS 78735
ATTORNEY DOCKET NUMBER:	AM21213TP
NAME OF SUBMITTER:	DEE MATOCHA
SIGNATURE:	/Dee Matocha/
DATE SIGNED:	01/23/2015
Total Attachments: 6	
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ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **SATOSHI SEKINE, an individual; and, CHEONG MIN HONG, an individual**, have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, State of Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America in and to certain inventions relating to improvements in **NON-VOLATILE MEMORY (NVM) CELL AND DEVICE STRUCTURE INTEGRATION** (Docket No. **AM21213TP**), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.**

We agree that, when requested, we will, without charge to **FREESCALE SEMICONDUCTOR, INC.**, but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives or nominees.

We covenant with **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.

AM21213TP

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Satoshi Sekine
SATOSHI SEKINE

DATE: 12-30-2014

First Witness

Yuko Sekine
SIGNATURE OF WITNESS

DATE: 12-30-2014
(Month-Day-Year)

YUKO SEKINE
PRINTED NAME OF WITNESS

4-18-9, Katsura, Izumi-ku, Sendai, Miyagi 981-3134 Japan.
PRINTED ADDRESS OF WITNESS

Second Witness

Saori Sekine
SIGNATURE OF WITNESS

DATE: 12-30-2014
(Month-Day-Year)

SAORI SEKINE
PRINTED NAME OF WITNESS

4-18-9, Katsura, Izumi-ku, Sendai, Miyagi 981-3134 JAPAN
PRINTED ADDRESS OF WITNESS

CHEONG MIN HONG

DATE: _____

STATE OF TEXAS)
)
COUNTY OF TRAVIS)

The undersigned Notary Public in and for the County and State aforesaid does hereby certify that CHEONG MIN HONG, whose name is subscribed to the foregoing instrument, appeared before me this day in person and acknowledged that they signed, sealed and delivered the instrument as their free and voluntary act and deed for the uses and purposes therein set forth.

Given under my hand and notarial seal this ____ day of _____, 2014.

My commission expires:

Notary Public Signature

AM21213TP

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PATENT
REEL: 034803 FRAME: 0345

ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **SATOSHI SEKINE, an individual; and, CHEONG MIN HONG, an individual**, have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, State of Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America in and to certain inventions relating to improvements in **NON-VOLATILE MEMORY (NVM) CELL AND DEVICE STRUCTURE INTEGRATION** (Docket No. **AM21213TP**), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.**, for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.**

We agree that, when requested, we will, without charge to **FREESCALE SEMICONDUCTOR, INC.**, but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives or nominees.

We covenant with **FREESCALE SEMICONDUCTOR, INC.**, its successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.

AM21213TP

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SATOSHI SEKINE

DATE: _____

First Witness

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

PRINTED ADDRESS OF WITNESS

Second Witness

SIGNATURE OF WITNESS

DATE: _____
(Month-Day-Year)

PRINTED NAME OF WITNESS

PRINTED ADDRESS OF WITNESS

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Cheong Min Hong

CHEONG MIN HONG

DATE: DECEMBER 10, 2014

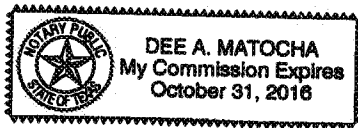
STATE OF TEXAS)
)
COUNTY OF TRAVIS)

The undersigned Notary Public in and for the County and State aforesaid does hereby certify that CHEONG MIN HONG, whose name is subscribed to the foregoing instrument, appeared before me this day in person and acknowledged that they signed, sealed and delivered the instrument as their free and voluntary act and deed for the uses and purposes therein set forth.

Given under my hand and notarial seal this 10th day of December, 2014.

My commission expires:

Dee A. Matocha
Notary Public Signature



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